# NSN 5961-01-086-9449

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Ceramic and metal

#### **Overall Length:**

Between 0.425 inches and 0.435 inches

#### **Overall Height:**

Between 0.095 inches and 0.105 inches

#### **Overall Width:**

Between 0.295 inches and 0.305 inches

# Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

1.5 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

3 pin

#### **Specification Data:**

80131-release6422 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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